

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _C = +25°C |
|-------------------|-------------------------------|--|
| 60V | 19mΩ @ V _{GS} = 10V | 33.2A |
| | 28mΩ @ V _{GS} = 4.5V | 28A |

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

PowerDI5060-8 (Type C)

- Engine management systems
- Body control electronics
- DC-DC converters

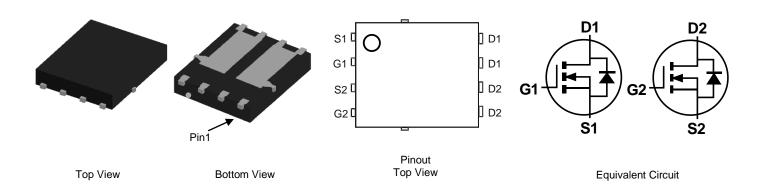
Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6016LPDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

| Part Number | Backaga | Packing | | |
|-----------------|------------------------|---------|-------------|--|
| | Package | Qty. | Carrier | |
| DMTH6016LPDQ-13 | PowerDI5060-8 (Type C) | 2,500 | Tape & Reel | |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

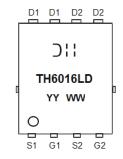
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



);; = Manufacturer's Marking TH6016LD = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 24 = 2024) WW = Week (01 to 53)

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|--|------------------|-----------------|--------------|----|
| Drain-Source Voltage | VDSS | 60 | V | |
| Gate-Source Voltage | V _{GSS} | ±20 | V | |
| Continuous Drain Current (Note 6) $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$ | | ID | 33.2 23.7 | A |
| Continuous Drain Current (Note 5) $T_{A} = +25^{\circ}C$ $T_{A} = +100^{\circ}C$ | | ID | 9.2 6.5 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | ldм | 50 | А | |
| Maximum Continuous Body Diode Forward Current (Note 5) | ls | 31 | А | |
| Pulsed Body Diode Forward Current (Note 5) | I _{SM} | 50 | А | |
| Avalanche Current, L = 0.1mH | | I _{AS} | 15.3 | А |
| Avalanche Energy, L = 0.1mH | | Eas | 11.7 | mJ |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit | |
|---|--------|----------|-------------|----|
| Total Power Dissipation (Note 5) T _A = +25°C | | PD | 2.5 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | Roja | 58 | °C/W | |
| Total Power Dissipation (Note 6) T _C = +25°C | | PD | 37.5 | W |
| Thermal Resistance, Junction to Case (Note 6) | Røjc | 4 | °C/W | |
| Operating and Storage Temperature Range | | TJ, TSTG | -55 to +175 | °C |

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad).



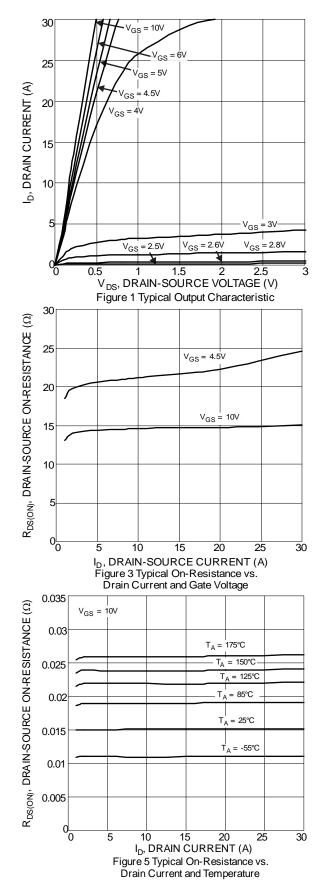
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

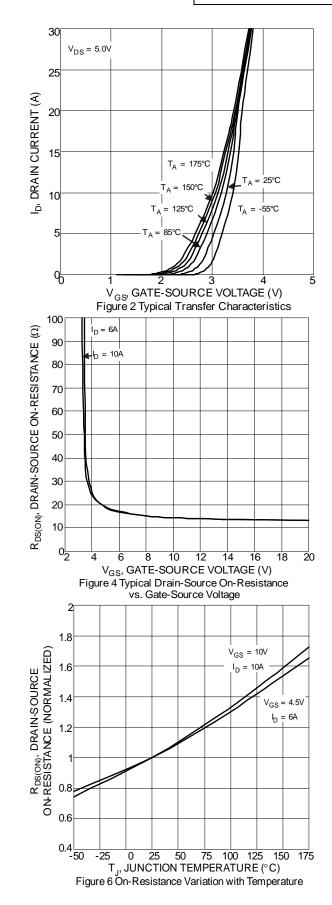
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|--------------------|-----|------|------|-------|---|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BVDSS | 60 | — | — | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current | IDSS | _ | — | 1 | μA | V _{DS} = 48V, V _{GS} = 0V | |
| Gate-Source Leakage | I _{GSS} | | — | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | VGS(TH) | 1 | _ | 2.5 | V | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | Proven | _ | 14.5 | 19 | mΩ | V _{GS} = 10V, I _D = 10A | |
| Static Drain-Source Of-Resistance | RDS(ON) | — | 20.9 | 28 | 11152 | $V_{GS} = 4.5 V, I_D = 6 A$ | |
| Diode Forward Voltage | Vsd | _ | 0.7 | 1.2 | V | V _{GS} = 0V, I _S = 20A | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | CISS | — | 864 | _ | pF | | |
| Output Capacitance | Coss | _ | 282 | — | pF | VDS = 30V, VGS = 0V, f = 1MHz | |
| Reverse Transfer Capacitance | Crss | _ | 27 | — | pF | | |
| Gate Resistance | Rg | _ | 1.3 | — | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Q _G | | 8.4 | — | nC | | |
| Total Gate Charge (V _{GS} = 10V) | QG | | 17 | — | nC | | |
| Gate-Source Charge | Qgs | | 3.1 | — | nC | V _{DS} = 30V, I _D = 10A | |
| Gate-Drain Charge | Qgd | | 4.3 | — | nC | 1 | |
| Turn-On Delay Time | t _{D(ON)} | _ | 3.4 | — | ns | | |
| Turn-On Rise Time | tR | | 5.2 | — | ns | $V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 10A, R_G = 6\Omega$ | |
| Turn-Off Delay Time | tD(OFF) | | 13 | — | ns | | |
| Turn-Off Fall Time | tF | _ | 7 | — | ns | | |
| Body Diode Reverse Recovery Time | trr | _ | 22 | — | ns | | |
| Body Diode Reverse Recovery Charge | Qrr | _ | 11 | _ | nC | —I _F = 10A, di/dt = 100A/μs | |

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



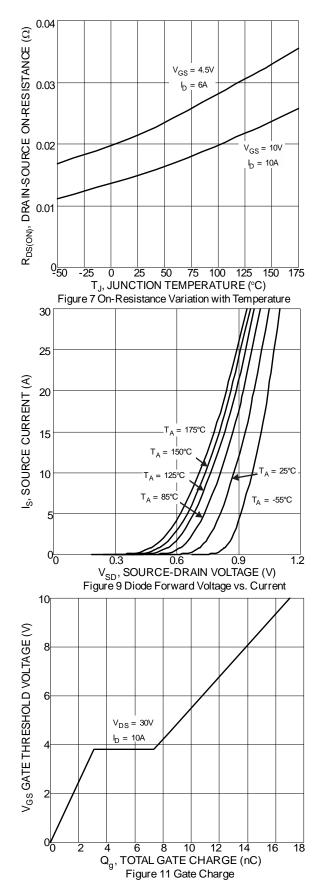
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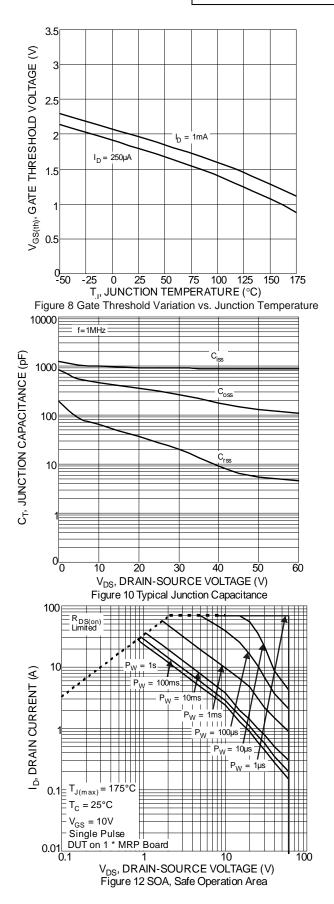




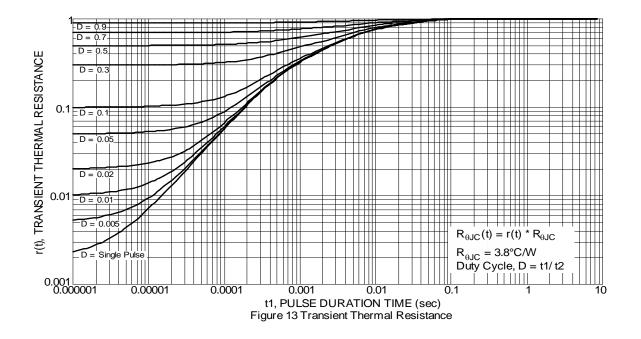
DMTH6016LPDQ Document number: DS39429 Rev. 4 - 2







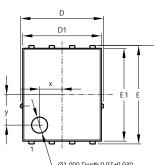






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



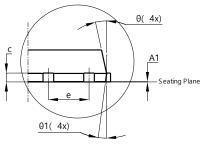
b1(8x)

E 2

La

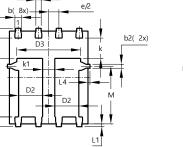


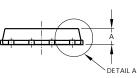




PowerDI5060-8 (Type C)

DETAIL A

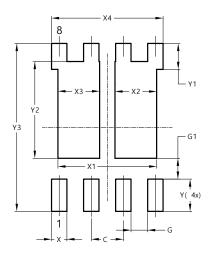




| PowerDI5060-8 (Type C) | | | | | |
|------------------------|-------|---------|-------|--|--|
| Dim | Min | Max | Ту́р | | |
| Α | 0.90 | 1.10 | 1.00 | | |
| A1 | 0 | 0.05 | 0.02 | | |
| b | 0.33 | 0.51 | 0.41 | | |
| b1 | 0.300 | 0.366 | 0.333 | | |
| b2 | 0.20 | 0.35 | 0.25 | | |
| c | 0.23 | 0.33 | 0.277 | | |
| D | 5 | .15 BS0 | 0 | | |
| D1 | 4.85 | 4.95 | 4.90 | | |
| D2 | 1.40 | 1.60 | 1.50 | | |
| D3 | - | - | 3.98 | | |
| Е | 6 | .15 BS0 | C | | |
| E1 | 5.75 | 5.85 | 5.80 | | |
| E2 | 3.56 | 3.76 | 3.66 | | |
| e | 1 | .27BSC | | | |
| k | - | - | 1.27 | | |
| k1 | 0.56 | - | - | | |
| L | 0.51 | 0.71 | 0.61 | | |
| La | 0.51 | 0.71 | 0.61 | | |
| L1 | 0.05 | 0.20 | 0.175 | | |
| L4 | - | - | 0.125 | | |
| М | 3.50 | 3.71 | 3.605 | | |
| х | - | - | 1.400 | | |
| у | - | - | 1.900 | | |
| θ | 10° | 12° | 11° | | |
| θ1 | 6° | 8° | 7° | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8 (Type C)

| Dimensions | Value (in mm) | |
|------------|------------------|--|
| С | 1.270 | |
| G | 0.660 | |
| G1 | 0.820 | |
| Х | 0.610 | |
| X1 | 3.910 | |
| X2 | 1.650 | |
| X3 | 1.650 | |
| X4 | 4.420 | |
| Y | 1.270 | |
| Y1 | 1.020 | |
| Y2 | 3.810 | |
| Y3 | 6.610 | |

DMTH6016LPDQ Document number: DS39429 Rev. 4 - 2



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